

SMPD - extreme flexible platform

MOSFET & Diode building blocks

MOSFETs

Type	Configura-tion	Circuit diagram / Technology	V_{DSS}	I_{D25} $T_c = 25^\circ C$	$R_{DS(on)}$ typ. $T_c = 25^\circ C$	NTC	Fig. No.
➢ New ✧ under development							
➢ MMIX 1T600N04T2	single	A Trench2	40	600	1.3		X031a
✧ MMIX 1T550N055T2	single	A Trench2	55	550	1.3		
➢ MMIX 1F520N075T2	single	A Trench2 HiPerFET	75	500	1.6		
➢ MKE 38RK600DFELB	buck/boost	C CoolMOS™ & FRED	600	50	40		X030a
➢ MKE 38P600LB	phase-leg	B CoolMOS™		50	40		
✧ MKE 38P600TLB	phase-leg	B CoolMOS™		50	40	*	

CoolMOS™ is a trademark of Infineon Technologies

Diodes

Type	Configura-tion	Circuit diagram / Diode type	Voltage	$I_{D(AV)M}$ $T_c = 90^\circ C$	NTC	Fig. No.
➢ New ✧ under development						
➢ DSA 120X150LB	dual	K Schottky	150	2x 75		X030a
✧ DHG 60U1200LB	3~ bridge	M SONIC	1200	63		
➢ DLA 100B1200LB	1~ bridge	L Rectifier	1200	124		
✧ DMA 90U1800LB	3~ bridge	M Rectifier	1800	99		

ISOLPLUS-SMPD™

